



Docket No.
90065.001020/17732.8011.00

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

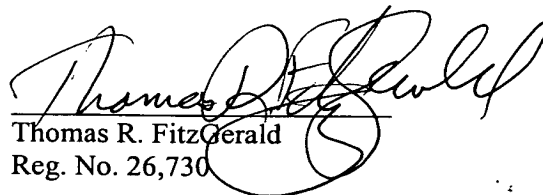
Applicant	: Martin E. Kordes, et al.) Examiner:
Serial No.	: 09/682,151) Chris C. Chu
Filed	: 27 July 2001) Art Unit:
For	: CONTACT METHOD FOR THIN SILICON) 2815
	CARBIDE EPITAXIAL LAYER AND)
	SEMICONDUCTOR DEVICES FORMED BY)
	THOSE METHODS)

Assistant Commissioner for Patents
Washington, DC 20231

TRANSMITTAL LETTER

In response to the office action mailed January 2, 2003, Applicants hereby submit the attached supplemental Declaration in connection with the above-referenced patent application.

Respectfully submitted,


Thomas R. FitzGerald
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2815

CERTIFICATE OF MAILING BY FIRST CLASS MAIL (37 CFR 1.8)

Applicant(s): Martin E. Kordes, et al.

Docket No.

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Serial No.
09/682,151

Filing Date
July 27, 2001

Examiner
Chris C. Chu

Group Art Unit
2815

Invention: CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS



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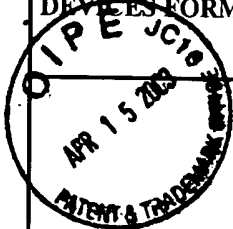
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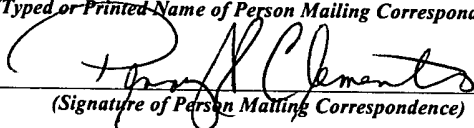
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2815Invention: CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR
DEVICES FORMED BY THOSE METHODSI hereby certify that this Supplemental Declaration (executed, 4 pages)
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